

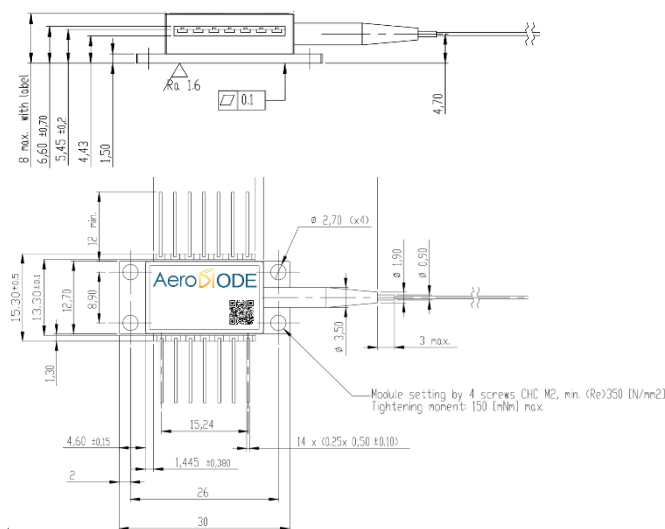
790 nm laser diode

250 mW / singlemode fiber / butterfly package

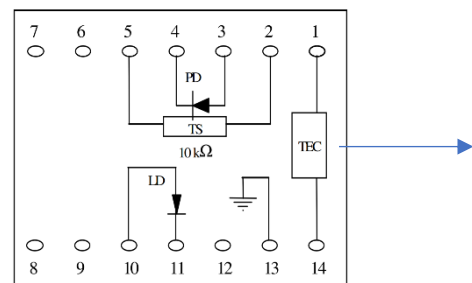
Reference: 790LD-1-SM/PM-NI

SPECIFICATIONS	Unit	Min	Typ	Maximum
Output Power	mW	200	250	
Center Wavelength (OPTION 2: FBG version)	nm	785 (791)	790 (792)	795 (793)
Spectral Width (FWHM) / (OPTION 2: FBG version)	nm		1 (0.2)	
Threshold Current	mA		65	100
Operating Current	mA		400	600
Operating Voltage	V		1.8	2.0
Wavelength shift w Temperature (OPTION 2: FBG version)	nm/°C		0.3 (5 10 ⁻³)	
Wavelength shift w Current (OPTION 2: FBG version)	nm/A		5 (~0)	
Side mode suppression ratio (OPTION 2: FBG version)	dB		(30)	
Internal photodiode responsivity	mA/W	0.04	3	10
Internal photodiode dark current	nA		5	40
TEC current (25°/case@70°)	A		1.1	
TEC voltage (25°/case@70°)	V		1.9	
Internal thermistor (25°)	kOhm	9.5	10	10.5
Fiber type (OPTION 1 : PM fiber)	Hi780 or equivalent (PM780 or equivalent)			
Fiber bend radius	mm	25		
Fiber connector	Yes (FC/APC)			
Storage temperature	°C	-40		85
Operating case temperature	°C	-20		70
Operating chip temperature	°C	20		40
Laser diode reverse voltage	V			2
Internal isolator	No			

Form factor:



Laser diode pinning:



Totally floating pin-out



Laser diodes are classified based on continuous operation - Contact us for any special requests regarding classification or power limitation.